- 1 The role of chemical design on the performance of organic semiconductors
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12 Abstract | Organic semiconductors are solution-processable, lightweight and flexible, such that they are increasingly being used as the active layer in a wide range of new technologies. The versatility of 13 synthetic organic chemistry enables the materials to be tuned such that they can be incorporated into 14 15 biological sensors, wearable electronics, semi-transparent photovoltaics and flexible displays. These devices can be improved not only by developing their synthetic chemistry but also by improving the 16 17 analytical and computational techniques that enable us to understand the factors that govern material properties. Judicious molecular design provides control of the semiconductor frontier molecular 18 orbital energy distribution and guides the hierarchical assembly of organic semiconductors into 19 20 functional films where we can control the properties and motion of charges and excited states. This Review describes how molecular design plays an integral role in developing organic semiconductors 21 22 for electronic devices in present and emerging technologies.

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- 24 [H1] Molecular orbital design considerations

The energies of frontier molecular orbitals and the distribution of the orbitals in a π -conjugated 25 molecule play critical roles in intra- and intermolecular charge transport, light absorption/emission. 26 27 charge injection/extraction/trapping and electrochemistry. This is true for organic small molecules and 28 conjugated polymers alike. In each case, the energy of the highest occupied molecular orbital (HOMO) 29 largely depends on the electron density and delocalization of the π electrons throughout a π -30 conjugated backbone. Substituents that donate electron density mesomerically (for example, lone pair donation from N, O or S heteroatoms) or inductively (for example, alkyl chains) can contribute to 31 raising the HOMO energy E_{HOMO} , decreasing the solid-state ionization potential (IP, Box 1). 32 Conversely electron-withdrawing groups, such as -F, -C(O)R or -C≡N groups, can act to lower both 33 34 the HOMO and lowest unoccupied molecular orbital (LUMO) energy, leading to an increase in the 35 solid-state electron affinity (EA).

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The spatial distribution of a molecular orbital is important when considering intermolecular electronic coupling, which relies on efficient π -orbital overlap between two or more conjugated systems. The rational introduction of substituents into a conjugated organic molecule is a practical means to manipulate molecular orbital energies levels. (Fig. 1).

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As a starting point to illustrate 'molecular engineering', (5Z,5'Z)-5,5'-(((6,6,12,12-tetramethyl-6,12-dihydroindeno[1,2-b]fluorene-2,8-diyl)bis(benzo[c][1,2,5]thiadiazole-7,4-

diyl))bis(methanylylidene))bis(3-ethyl-2-thioxothiazolidin-4-one) (IDFBR, Fig. 1) was chosen. The 44 45 HOMO wavefunction is delocalized over its entire π -conjugated backbone whereas in contrast, the 46 LUMO wavefunction is predominantly localized on the electron-deficient 2,1,3-benzothiadiazole (BT) 47 and rhodanine moieties.¹ In order to efficiently accept electrons from a light absorbing donor polymer, we are interested in tuning the LUMO energy of IDFBR, which is optimally achieved by the 48 introduction of substituents at its periphery. To tune the HOMO energy however, we can add 49 50 substituents at any conjugated part of the molecule. Replacing the central indenofluorene core with a 51 smaller fluorene unit affords FBR, which has fewer delocalised electrons, resulting in an increase in 52 HOMO energy (by almost 0.2 eV), with a smaller increase in the LUMO energy (less than 0.1 eV), 53 due to the larger fraction of the conjugated unit having electron withdrawing functionality. A 54 modification of **FBR** by replacing the BT units with a phenylene, results in **PH**, the LUMO energy of

55 which is substantially higher lying ($\sim 0.5 \text{ eV}$) because the phenylenes are less electron-deficient (the 56 HOMO is only marginally affected). Difluorinating the BT units in FBR gives **diFBR**, in which both 57 the HOMO and LUMO energies are 0.1-0.2 eV lower lying on account of electron-withdrawing inductive effects of the electronegative F atoms. Another approach in the manipulation of the 58 molecular orbitals of FBR is to replace the C=S (thiocarbonyl) groups on the rhodanine periphery, 59 with dicyanovinyl moieties, which are more strongly electron-withdrawing than the thiocarbonyl. 60 61 Indeed, diCN has HOMO and LUMO energy levels that are ~ 0.3 eV lower than those of FBR. Both 62 the electron density distribution along the molecule, as well as the delocalization of the π orbitals play 63 a substantial role in determining the orbital energy levels. **FBR** has a non-planar backbone because the BT and fluorene units have neighbouring H atoms that participate in repulsive interactions. These 64 65 steric effects can be alleviated by replacing the fluorene core with cyclopentadithiophene to give **CPDT**, a molecule with more π orbital overlap between rings, which contributes to both raising the 66 HOMO energy and lowering the LUMO energy. The introduction of the electron-rich thiophene rings, 67 68 further raises the HOMO energy. CPDT also exhibits electrostatic S...F interactions, with these 69 electropositive and electronegative atoms, respectively, interacting to stabilise the planar backbone, affording additional raising of the HOMO energy and lowering of the LUMO energy. The greater π 70 71 orbital delocalization means that the LUMO is now distributed further over the core of the molecule, and functionalization at any location within this region will affect the LUMO as well as the HOMO 72 73 energy. Substituting the sp^3 -hybridized C atom of the fluorene unit with either Si or Ge does not appear to influence either the HOMO or LUMO energies. This is surprising because incorporating 74 75 larger heteroatoms between rings typically leads to a lengthening of the C-C bond linking the two aromatic rings, thereby attenuating the antibonding interactions that arise from the node of the HOMO 76 77 between the rings and lowering the HOMO energy. Similarly, replacing the S atoms on the CPDT unit with other chalcogen atoms does not affect the electronic structure of CPDT. In general, having a 78 79 larger chalcogen atom (E) in a ring lowers its aromatic character because the E–C bonds are longer, 80 such that the chalcogen non-bonding valence electrons are less delocalized. The ring thus has more diene character, such that the overall molecule has a lower lying HOMO and a smaller bandgap². 81

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Charge transport is sensitive to traps within the bulk,³ and transport within p-type materials benefits 83 from their low ionization potential, which makes the filling of deep traps thermodynamically 84 85 unfavourable. Similarly, n-type materials benefit from a large EA, when again there are less accessible charge traps. Injecting holes from an electrode into the HOMO of a semiconductor is more 86 energetically facile when the electrode workfunction is close to, or preferably larger than, the IP of the 87 88 semiconductor. This allows for ohmic contact, with low contact resistance at the electrodesemiconductor interface. Correspondingly, for electron injection, the EA should be as large as 89 possible. For an organic semiconductor device to be stable in operando, we must ensure that its 90 neutral and charged forms do not participate in chemical reactions.⁴ In order to prevent the most 91 thermodynamically favourable reactions (those involving a combination of O_2 and H_2O), a neutral p-92 type semiconductor is predicted to require an ionization potential greater than 4.9 eV.⁴ When this is 93 not the case, the shallow HOMO semiconductor can, for example, reduce ambient O₂ in the presence 94 95 of H₂O to form OH⁻. Under operation, deep HOMO semiconductors can accept holes that can oxidise 96 atmospheric H₂O. The activation barriers of these deleterious reactions fortunately lead to 97 overpotentials that allow many organic semiconductors to perform redox slowly so they can exhibit 98 reasonable shelf and operational stabilities. Electron transport is particularly affected by reactions with air, and it is essential to prevent the electron polaron from reducing ambient species. To 99 100 accomplish this, the LUMO energy must be low enough to prevent excited electrons to reduce hydrated O_2 complexes to O_2^- (one of the most favourable electrochemical reactions)⁵ or H₂O to OH⁻. 101 These unwanted electrochemical processes can lower charge transport and also lead to further 102 103 irreversible reactions within a semiconductor. Defining a precise EA value that needs to be exceeded 104 to prevent these redox reactions requires consideration of the overpotential of the reaction and device morphology. It has been proposed that organic molecules should have an EA greater than 4 eV to 105 suppress oxidation reactions⁶. 106

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108 [H1] Organic field effect transistors

109 Charge transport in organic semiconducting polymers relies on a combination of intrachain polaron 110 conjugation, facilitated by π -electron delocalization across the polymer backbone, and intermolecular 111 charge-hopping between adjacent chains, facilitated by thin film microstructure. Charge carrier 112 mobility is very sensitive to the nature of the close-packed hierarchical assembly of polymer 113 backbones, which can be optimized by tuning inter- and intramolecular interactions. Intermolecular 114 contacts have been facilitated by many design motifs, including the µm-scale 3D ordering of 115 poly {2,5-bis(3-alkylthiophen-2-yl)thieno[3,2-b]thiophene} (**pBTTT**, Fig. 2a) in thin films'. This 116 material adopts a morphology in which ordered lamellar sheets of π -stacked conjugated **pBTTT** 117 backbones exhibit out-of-plane order or "registration" directed by the interdigitation of vertically 118 adjacent polymer chains. Interdigitation was made possible by the conformationally-tolerant, regular 119 spacing of the side chains along the backbone, with optimal spatial separation to ensure an ordered 120 and close-packed side chain density on interdigitation.

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122 The approach of utilising non-covalent intermolecular interactions for charge transport optimisation, 123 has subsequently been exploited in a series of isoindigo polymers⁸, and a comparison drawn with 124 similar associations observed in biology. Here the polymer alkyl side chains were described as 125 undergoing 'molecular docking', the locking of side chains into voids along the polymer chain Indeed, 126 the collective van der Waals interactions between inert aliphatic side chains are the dominant 127 interaction that governs morphology and inter- and intrachain contacts. Even though the degree of 128 interdigitation exhibited by **pBTTT** is extremely unusual, a close packed and regular alkyl 129 distribution between backbones can act to not only order a material, but also minimize the local free 130 volume such that unwanted species such as H₂O are excluded. If these small molecules were included 131 then they could participate in charge-trapping and lower carrier mobility.

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133 Intramolecular charge transport can be optimally facilitated when the backbone of a polymer has the 134 least possible amount of intrinsic energetic disorder, in which case it is resilient to torsional fluctuations between adjacent monomer units^{9,10}. Energetic disorder is typically minimized by 135 maximising the energetic barrier to rotation between aromatic repeat units along the backbone. 136 137 Several design strategies can impart coplanarity of adjacent monomer units in a conjugated backbone. 138 Non-covalent through-space interactions between adjacent rings can act as a barrier to rotation, thus 139 promoting co-planarity. Common examples of this approach include the electrostatic attractions 140 between heteroatoms in close proximity to the bond linking two aromatic rings in the backbone. The S 141 atom on a linking thieno group, despite the presence of two lone pairs of electrons, presents a partially 142 positive charge due to the donation of one lone pair to complete an aromatic ring. As a result, 143 heteroatoms such as O and N, which have available lone pairs of electrons, can participate in strong attractive interactions with S, leading to a more rigid structure.¹¹⁻¹³ For example, in poly(3-144 alkoxythiophene) the S atom of one ring interacts with the more electronegative O atom in the 145 146 adjacent ring (Fig. 3a). Other planarizing interactions include H-bonding interactions, which are 147 observed between bis(lactam) building blocks and neighbouring residues. Thus, the crystal structures 148 of small-molecule diketopyrrolopyrrole (DPP) and isoindigo derivatives feature O···H-C interactions.^{14,15} The O atom in the electron-deficient lactam core interactions with a proximal H atom 149 150 to lower rotational disorder and maximize π -orbital overlap between the rings. This concept can be 151 extended to polymers by incorporating DPP and isoindigo monomers into the polymer backbone (Fig. 152 3a).

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154 Non-covalent interactions can also be exploited to design highly coplanar copolymers with low 155 energetic disorder such as the copolymer poly(indacenodithiophene-co-benzothiadiazole) (IDT-BT, 156 Fig. 2b)⁹. The dominant planarising interaction in this case is a H-bond between the N atom of the 157 benzothiadiazole and the α -H atom of the adjacent indacenodithiophene. These strong N···H–C 158 interactions outweigh the repulsive steric exchange energies associated with planarity, giving rise to 159 extremely low energetic disorder in this polymer. Despite the high coplanarity, the polymer exhibits a 160 hierarchical structure resembling a curved ribbon, and disordered over larger length scales, but the 161 assembly of side chains promotes intermittent short contacts along the backbone. Thus, although 162 charge is primarily transported in 1D along the backbone, there are occasional hops between chains 163 such that these short contact polymers exhibit very high carrier mobilities.

164 165 The above discussion has described organic polymers for charge transport, but small molecule semiconductors can also serve the same purpose in electronic devices. However, transport properties 166 167 have been notoriously difficult to optimise through rational design at the molecular level. Crystal 168 packing motifs play a dominant role and are extremely sensitive to even the smallest molecular 169 perturbations. The herringbone and 2D slip-stack arrangements in particular have the required 170 combination of electronic coupling and sufficient isotropy for efficient charge propagation. Two key 171 building blocks have emerged as exemplary aromatic cores: pentacene (and its analogue 172 anthradithiophene (ADT)) and benzothiophene (BTBT). The packing motifs of these 173 semiconducting molecules have been manipulated by strategically introducing substituents either on 174 the central core (in the case of pentacene and ADT) or periphery (in the case of BTBT). Both 175 pentacene and ADT can be readily functionalized, with the 6 and 13 positions of pentacene¹⁶ and 5 176 and 11 positions of ADT being the most conveniently substituted. In this way, one can prepare species such as the bis((trialkylsilyl)ethynyl) derivatives **TIPS-pentacene** and **TES-ADT** (Fig. 3b). 177 178 Introducing the $-C \equiv C - SiR_3$ groups increases solubility in organic solvents, blocks a possible site of 179 oxidative degradation, and also adds a structural template that promotes 2D interdigitated π -stacking. 180 This morphology is favourable in that it can give rise to thin films with higher charge carrier 181 mobilities than most other packing motifs. Replacing the ⁱPr groups in **TIPS-pentacene** with Et 182 groups changes the preferred packing structure to a lamellar 1D slip stack with a much larger charge 183 transport anisotropy. Over the length scale of a transistor device, this leads to much lower charge 184 carrier mobilities. In the case of **TES-ADT**, the inclusion of a peripheral F atom can promote short non-covalent contacts, further enhancing electronic coupling and, consequently, carrier mobility. 185 186 BTBT has been identified as a suitable aromatic core for charge transport and is most easily substituted at the 2 and 7 positions, for example with linear ${}^{n}C_{8}H_{17}$ chains¹⁷. These chains increase 187 solubility in organic solvents and have a highly calamitic (rod-like) shape that makes C₈-BTBT adopt 188 189 a favourable herringbone packing motif. The short contacts between the conjugated cores of adjacent 190 molecules in the crystal give rise to excellent and relatively isotropic electronic coupling, thus 191 enhancing charge carrier mobility. Historically, the charge carrier mobilities observed in small 192 molecule films have been larger than those in polymer films, and this has been attributed to the former 193 having a lower energetic disorder, narrower density of states, and fewer defects. However, the 194 performances of semiconducting polymers with short intermolecular contacts are catching up, and 195 they generally exhibit lower charge transport anisotropy, which makes them potentially favourable for 196 integrated circuitry.

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[H1] Organic photovoltaics

199 An organic photovoltaic (OPV) device includes a photoactive layer consisting of an electron donor 200 and an electron acceptor. Both these materials can be tailored on a molecular level such that they 201 absorb a large proportion of incident solar irradiation. An appropriate energetic offset between 202 frontier orbitals of the donor and acceptor enables the splitting of excitons into free charge carriers, 203 which can be collected at the separate electrodes. To absorb a large fraction of incident photons, an 204 active layer substantially thicker than the exciton diffusion length is required, which, in turn, necessitates an intermixed donor:acceptor bulk heterojunction (BHJ, FIG. 4a) morphology.¹⁸⁻²⁰ 205 206 Optimizing frontier molecular orbital energies of the donor and acceptor to increase the energetic driving force for charge separation and open circuit voltage (V_{oc}) must be balanced against efficient 207 light absorption. Additionally, the donor: acceptor heterojunction must be judiciously controlled 208 209 throughout the active layer to ensure efficient charge separation and collection with a high degree of 210 morphological stability.

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We now describe selected pairs of organic donor (FIG. 4b) and acceptor materials (FIG. 4c) in the context of a BHJ. In the extensively studied **P3HT**:**PCBM** heterojunction the LUMO energy levels are ~-3.2 and -4.2 eV for **P3HT** and **PCBM**, respectively, providing a large energetic offset to overcome the **P3HT** exciton binding energy (typically 0.3 eV) and drive charge separation through a Channel-I mechanism (Fig. 4a).This driving force, combined with the strong visible light absorption of **P3HT** and the favourable intermixed morphology of the BHJ, means that OPV devices can have power conversion efficiencies over 4%.²¹ 219 220 To harvest a greater proportion of the solar spectrum, OPV research rapidly shifted from using **P3HT** 221 to instead designing electron donors with hybridized molecular orbitals from having alternating π -222 conjugated electron-rich and electron-poor repeat units. This effective and highly modular paradigm 223 has been employed repeatedly to narrow the HOMO-LUMO gap and develop vast numbers of push-224 pull-type polymers with hybridized molecular orbitals. While a narrower-bandgap donor will absorb a 225 greater proportion of the incoming photons and thus increase the extracted current (J_{sc}) , it can 226 compromise either the Voc (shallower donor HOMO leading to smaller LUMOacceptor-HOMOdonor gap) or the charge separation (deeper donor LUMO leading to smaller LUMO_{donor}-LUMO_{acceptor} offset) 227 according to Figure 4a. Computational modelling suggests that the compromise between high voltage 228 and efficient light absorption is best negotiated in a PC60BM-based device using a donor material 229 with a band gap around 1.5 eV.^{22,23} One such material is **PCPDTBT**, which, despite having a near 230 ideal band gap, performed poorly in bulk heterojunction devices. However, in 2007, the efficiency of 231 232 a **PCPDTBT**:**PC**₇₀**BM** device was nearly doubled from 2.8 to 5.5% by adding a small amount of 1.8octanedithiol when casting the active layer.²⁴ The dithiol preferentially improves the solubility of one 233 234 of the photoactive components during film casting, enabling the bulk heterojunction morphology to be 235 optimized and hence facilitating more reliable assessment of new photoactive materials without 236 performance being overshadowed by poor morphology. Thus, by using push-pull-type narrow-237 bandgap donor polymers in conjunction with fullerene-based acceptors, the field steadily developed to 238 being able to fabricate OPV devices with efficiencies up to $\sim 11\%$. The donor materials often featured 239 the non-covalent interactions discussed above, which promote polymer aggregation and facilitate phase separation on the exciton diffusion lengthscale.²⁵ From a frontier molecular orbital perspective, 240 the HOMO energies of polymers such as PTB7 (-5.15 eV), PTB7-Th (-5.24 eV) and PffBT4T 241 (-5.34 eV) have been lowered to improve V_{oc} , while the bandgap has been increased slightly to 242 ~1.6 eV. It should be noted that most high-performing PCBM devices are prepared not with PC₆₀BM 243 as the acceptor, but using the C₇₀ derivative PC₇₀BM, the lower symmetry of which allows stronger 244 visible light absorption and greater channel-II photocurrent generation (Fig. 4a).²⁶ 245

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247 Polymeric electron donors have dominated the OPV landscape, but there are some notable smallmolecule electron donors. The pyridalthiadiazole-based small molecule p-DTS(PTTh₂)₂ (Fig. 4b; 248 $E_{\text{LUMO}} = -3.6 \text{ eV}; E_{\text{HOMO}} = -5.2 \text{ eV}$) absorbs in the broad 500–800 nm region and has a large LUMO– 249 LUMO offset when paired with PC₇₀BM.²⁷ Controlling the blend morphology in a two molecule 250 blend is challenging, as evidenced by the performance of p-DTS(PTTh₂)₂:PC₇₀BM devices being 251 252 remarkable sensitive to processing conditions. A 70:30 donor: acceptor weight ratio with 0.25% 253 solvent additive affords a power conversion efficiency of 6.7%. Small deviations from this 254 composition see the performance drop precipitously.

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The difference between the optical energy gap and the observed open-circuit voltage V_{oc} is referred to as the V_{oc} loss. This quantity is substantial for fullerene-based OPV devices that predominantly 256 257 operate by a channel-I mechanism. Losses in high-performance PCBM cells are typically on the order 258 of 0.8 eV — a value substantially larger than the exciton binding energy.²⁸ Using a non-fullerene 259 acceptor (NFA) addresses this crucial barrier to further improving OPV device efficiencies. Although 260 261 it is relatively straightforward to design and synthesise NFAs with appropriate HOMO and LUMO 262 energy levels, early work highlighted the difficulties achieving both an intermixed blend morphology 263 and sufficiently high charge carrier mobilities. For example, the high crystallinity of rylene diimides 264 can preclude blending but has been mitigated by using twisted dimer-type acceptor structures. Indeed, 265 the Se-annulated PDI motif in SdiPBI-Se can be used to achieve a PCE of 8.4%, and the four-blade propeller-type structure **FTTB-PDI4** gives rise to a higher PCE of 10.6% with a low V_{oc} loss of 0.53 266 $V^{29,30}$ NFAs are more tunable than fullerenes in terms of frontier orbital energies, with SdiPBI-Se 267 $(E_{\text{LUMO}} = -3.9 \text{ eV}; E_{\text{g}} = 2.2 \text{ eV})$ and **FTTB-PDI4** $(E_{\text{LUMO}} = -3.6 \text{ eV}; E_{\text{g}} = 1.9 \text{ eV})$ being two notable 268 examples. The acceptor strength can be adjusted to match the chosen donor material, and E_{g} can 269 likewise be tuned to ensure complementary absorption with the donor. The control over frontier 270 271 orbital energies of NFAs is further emphasized when one notes that their HOMOs and LUMOs are 272 often spatially separated (FIG. 1), meaning that they can be adjusted independently of each other 273 through molecular design. Additionally, NFAs typically have better light absorption than fullerene acceptors, and combined with the efficient hole transfer from acceptor to donor, this provides high channel-II photocurrent generation and high J_{sc} values.

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277 A recently developed NFA design is a calamitic π -conjugated molecule with a central fused electron-278 rich (hetero)aromatic core flanked by terminal electron-deficient units such as indanedione or 279 rhodanine. Further modularity in the molecular design can be incorporated by introducing electron-280 rich or electron-deficient π -conjugated spacers between the core and the flanking groups. **IDTBR** 281 (FIG. 4c), which features an indacenodithiophene core flanked on each side by 2,1,3-benzothiadiazole and rhodanine, is one such calamitic acceptor.³¹ The aromatic groups in its backbone are coplanar, 282 such that **IDTBR** has a relatively narrow E_g (1.6 eV) and a **P3HT**:**IDTBR** active layer consequently 283 absorbs strongly over the entire visible spectrum to give devices with efficiencies above 6%. In 284 285 addition to improving the OPV performance of a simple and commercially scalable polymer such as 286 **P3HT**, this result also illustrates that NFAs can be used as the primary low-bandgap light absorber, a 287 role which was hitherto reserved for the donor material. Further improvements towards 8% power conversion efficiency with IDTBR has been reported for ternary blends using two complementary 288 NFAs in conjunction with **P3HT**.³² Further, **IDTBR** has an electronic structure ($E_{LUMO} = -3.9 \text{ eV}$) 289 that is compatible, in terms of LUMO-LUMO offset, with donor polymers such as PffBT4T. Indeed, 290 a PffBT4T:IDTBR-based device can exhibit a power conversion efficiency of 10% and a very small 291 $V_{\rm oc}$ loss (~0.5 V).³³ **ITIC** is another calamitic acceptor with comparable frontier orbital energy levels 292 to those of IDTBR.³⁴ Likewise, ITIC has been used in several high-efficiency OPV devices, but as 293 with **IDTBR** its optical bandgap ($E_g \approx 1.6 \text{ eV}$) is comparable to most high-performing donor polymers 294 295 developed specifically for fullerene-based devices. Thus, to absorb more broadly within the solar spectrum and increase J_{sc} it is beneficial to widen the bandgap of the donor polymer, so as to prevent a 296 297 large spectral overlap with the NFA and possibly open a pathway for Förster energy transfer from the donor to acceptor. For example, **PBDB-T** (FIG. 4b, $E_{HOMO} = -5.3 \text{ eV}$; $E_g \approx 1.8 \text{ eV}$) comprises the 298 299 weakly electron-deficient benzodithiophenedione unit in conjunction with the well-known electron-300 rich benzodithiophene motif. Being highly compatible with ITIC, this wider bandgap donor has been incorporated into devices, and the power conversion efficiencies of **PBDB-T**:**ITIC** active layers have gradually improved to over 14%.^{35,36} **PBDB-T** has been modified by replacing alkyl chains with 301 302 thioalkyls, as well as by fluorination and chlorination. Similarly, ITIC has been fluorinated and 303 304 chlorinated — modifications that make it a better electron acceptor by lowering the energies of both 305 the HOMO and LUMO. The bandgap is slightly narrowed because the lowering is greater for the 306 LUMO, on account of it being more distributed over the ITIC unit. This red-shifted absorption 307 increases the J_{sc} while enhanced intra- and intermolecular interactions concurrently improve the 308 extinction coefficient and charge-transport properties. Thus, the HOMO energy of the dichlorinated 309 derivative PBDB-T-2Cl is 0.2 eV lower than that of PBDB-T, which makes the former useful in 310 terms of affording OPV devices with high V_{oc} values with the active layer having good oxidative 311 stability on account of the low-lying frontier orbital energies.

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313 Most recently, the research community has looked beyond linear calamitic motifs to the curved structure Y6, a narrow bandgap NFA that absorbs strongly beyond 900 nm.³⁷ The central π -314 conjugated chromophore in this material is a 2,1,3-benzothiadiazole flanked by thieno[3,2-315 316 b]thiophene units that are fused onto the benzothiadiazole with N-alkylpyrrolo groups. The two alkyl 317 side chains face each other and their interactions give Y6 its slight twist ($\sim 17^{\circ}$), which ensures good 318 solubility and favourable control of aggregation. This electron acceptor, paired with a fluorinated 319 derivative of **PBDB-T** as the donor, can afford devices with power conversion efficiencies exceeding 320 15% and $V_{\rm oc}$ values above 0.8 V. The already small $V_{\rm oc}$ loss for this system can be further improved by using a chlorinated analogue of Y6, giving devices with efficiency above 16% and V_{oc} loss of only 321 0.53 V.³⁸ It is hypothesised that the much larger dipole moments in these bent NFAs compared to 322 323 ITIC-type NFAs, and the high electron mobility, contribute to efficient charge separation and fill 324 factors being around 75% — a high value that is desirable.

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The tunability of molecular structure and frontier orbital energies has driven the OPV field over the last decade and related design approaches are being explored to sensitise other PV applications. This is most notable in the development of singlet fission materials that convert one high-energy singlet exciton to two lower energy triplet excitons. In turn, these triplets can generate additional e^-h^+ pairs, for example, in low bandgap Si-based PV devices. With an S₁ singlet exciton energy of 2.4 eV, tetracene can absorb high-energy photons that would otherwise lead to high thermalization losses in Si cells, with subsequent singlet fission converting the singlet exciton into two triplet excitons. The T₁ triplet exciton energy of tetracene (~1.25 eV) nicely matches the bandgap of Si (1.1 eV). Although it is challenging to efficiently transfer the triplet excitons to the Si cell, this technology holds promise to exceed the Shockley–Queisser limit of 29% efficiency for a single junction PV device.

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337 [H1] Organic light-emitting diodes

Despite organic light emitting diodes (OLEDs) being at an advanced stage of commercialization, their 338 339 study remains an extremely active area of research in which many fascinating developments have 340 been reported over the last 5-10 years. The fundamental operating principle of an OLED is extremely 341 simple: charges injected from electrodes recombine within an organic layer to form an excited state 342 which decays radiatively. However, spin statistics dictate that recombination of free charges results in a 1:3 ratio of singlet and triplet excited states being generated. The vast majority of OLED research 343 344 has been targeted at overcoming the non-emissive nature of triplet excited states, a problem that 345 would limit internal quantum efficiency (IQE) to 25% — the fraction of excites states that are singlets. The first successful approach to overcoming this was to move away from fluorescent emitters (1st 346 generation materials, FIG. 5) to phosphorescent compounds (2nd generation). These compounds can 347 348 emit quickly because they feature heavy metals, which promote intersystem crossing (ISC) of the 349 triplets, as observed for organoplatinum and -iridium complexes (Fig. 5). This allowed all of the 350 electrically generated excited states to be used radiatively such that devices with 100% internal 351 quantum efficiency (with a maximum of 20-25% external quantum efficiency (EQE) due to 352 outcoupling losses) could be prepared. However, problems associated with colour purity and stability (particularly in the blue region) have motivated the development of better OLED materials. The newest OLED materials (3rd generation) exhibit reverse intersystem crossing (RISC) to use triplet 353 354 states. By lowering the energy gap between the lowest excited singlet and triplet states ($\Delta E_{\rm ST}$), the 355 356 system has enough thermal energy to undergo RISC and have its triplet state convert into an emissive singlet. This process has fittingly been referred to as thermally-activated delayed fluorescence (TADF) 357 358 and is a contemporary research topic of intense interest.

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360 The most commonly used phosphorescent emitters are cyclometallated Ir(III) complexes dispersed 361 within an organic host. It has long been known that the emitting dipole orientation of a dye influences the outcoupling efficiency (EQE/IQE) of OLEDs.³⁹ Despite this, the dipole orientations of 362 phosphoresecent dopants have not been studied extensively, presumably due to the lack of any 363 364 obvious driving force for alignment in (typically amorphous) host materials. However, a recent study using angle-dependent polarized photoluminescence emission spectroscopy shows that certain Ir complexes can be aligned in films.^{40,41} The inherent asymmetry at the surface of a growing film 365 366 apparently promotes dopant alignment in these otherwise amorphous films. Alongside other 367 368 investigations into controlling phosphor alignment, external quantum efficiencies in excess of 30% have been reported, and it is projected that efficiencies of up to 60% are possible.^{39,42} Despite decades 369 370 of research, new strategies for achieving efficient blue emission from Ir complexes are still being 371 sought with very impressive results emerging recently. Isomerizing a UV-emitting N-heterocyclic 372 carbene complex of Ir(III) from its fac to mer form subtly red-shifts its emission such that it exhibits 373 efficient deep blue phosphorescence with ~80% photoluminescence quantum yield (PLQY) and EQE ~15%.43 There has recently also been considerable progress in the development of Ir-free 374 375 phosphorescent emitters, including a new class of cyclometalated Au(III) complexes with tuneable 376 emission spanning sky-blue to red. When deposited as thin films, these materials exhibited high PLQY values of up to 80%, and the OLEDs have excellent stability while maintaining EQEs up to 377 22%.37 An extremely active area of research is the development of near-infrared OLED emitters for 378 379 security and communication applications. Examples of {Pt^I[3-(pyrazinyl)pyrazolato]₂} derivatives 380 emit at 740 nm with a PLQY of 81%, and adopts a highly preferred horizontal dipole orientation such that its OLED devices exhibited an external quantum efficiency of 24%.⁴⁴ The origin of the near-381 382 infrared emission has been attributed to the stacking of Pt(II) centres on top of each other in the solid 383 state, enabling metal-metal-to-ligand charge transfer.

384 385 Almost certainly the biggest development in OLED research over the last 10 years has been the 386 observation of TADF from purely organic dyes. This work was pioneered by the group of Adachi, 387 whose seminal publication described a series of purely organic materials such as 2,3,5,6-tetra(Ncarbazolyl)benzonitrile (Fig. 5) that afford tuneable emission with high PLQYs and OLED EQEs 388 approaching 20%.45 This work showed that the simple design concept of spatially separating a 389 molecule's HOMO and LUMO by using a twisted donor-acceptor structure lowers the energy gap 390 391 between the first excited singlet and triplet states. Thus, triplet states can convert into emissive 392 singlets by RISC, such that the materials exhibit TADF. By tuning the number, twist angle and 393 electron density of donor moieties linked to the acceptor(s), one can obtain a series of compounds that collectively exhibit extremely high PLQY and OLED EQEs from the blue to near infrared.^{46,47,48,49,50} 394 395 Despite these impressive results, the exact mechanism by which RISC and TADF occur remains the subject of debate. In order to design efficient TADF emitters it is vital to consider both locally excited 396 (LE) and charge-transfer (CT) states.⁵¹ However, the process by which singlet and triplet states 397 interconvert is not clear. 'Hidden' $n-\pi$ mixed states may play an important role in the process or it is 398 also possible that second-order vibronic coupling between the various excited states is required.⁵²⁻⁵⁴ 399 400 The role of intermediate electronic states that mediate the spin-flip through molecular vibrations has been demonstrated using a new model that also complements the notion of non-adiabatic coupling of 401 triplet states promoting ISC.⁵⁵ Therefore, the synthetic strategy of merely minimising the S_1-T_1 energy 402 gap requires refinement. One of the issues with conventional TADF is the requirement of donor-403 404 acceptor structures to be highly twisted, which results in broad spectral emission with low oscillator 405 strength. This can potentially be overcome using a "hyperfluoresence" strategy, whereby a fluorescent guest is introduced into a TADF host, albeit at the expense of device simplicity.⁵⁶ It has also been 406 suggested that a 'multi-resonant' strategy, that aims to spatially separate the HOMO and LUMO of a 407 single planar molecule, can afford narrow $\Delta E_{\rm ST}$ materials with high oscillator strengths and narrow 408 emission.^{57,58} Indeed, extremely impressive results using this strategy has recently been reported with 409 a blue (469 nm) organoboron TADF-based OLED with an EQE of 34%.⁵⁹ 410

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TADF has also been observed in organometallic systems, with $[Cu^{l}(NR_{2})(N-heterocyclic carbene)]$ complexes exhibiting outstanding optoelectronics properties (PLQY = 100%, EQE >25%).^{60,61} Emission in these systems appears to stem from interligand charge-transfer states and, importantly, it appears that (as has also been suggested for organic TADF emitters⁶²) that there is considerable spinmixing, further indicating that the spin-pure picture of TADF emitters may be simplistic. However, as with phosphoresecent OLED emitters, achieving highly stable blue OLEDs with good colour purity has proved extremely challenging.

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420 [H1] Beyond the state-of-the-art

421 A typical chemical design approach to optimize a semiconductor involves taking the conjugated 422 aromatic units comprising the core or backbone and introducing systematic variations to isolate and 423 study substituent effects on both morphology and frontier molecular orbitals. The results for the new 424 materials are often compared to those in previous publications to justify a new design. In transistor 425 research, unreliable charge carrier mobility values, extracted from invalid model equations and 426 assumptions, have inflated expectations. Moreover, they have led to incorrect structure-property 427 relationships being proposed, with molecular design conclusions reached on tenuous evaluations. This 428 body of erroneous and misleading literature has seriously impeded progress in the development of 429 materials for transistor applications. However, there are some obvious opportunities for further 430 exploration. Incorporating aliphatic chains in these materials is primarily done to impart 431 organosolubility, with a secondary reason being to control the solid-state structure. However, both 432 alkyl chain and lamellar crystallization can come at the expense of conjugated backbone planarity and 433 crystallinity. It is imperative that new semiconductors are designed in a holistic fashion, whereby the 434 self-assembly of the system works with optimum performance rather than against it. It may be possible to deploy side chains in creative new ways to suppress undesirable phonon modes, which 435 have recently been shown to severely affect charge transport.⁶³ Alternatively, removing the alkyl 436 437 chains altogether should fundamentally improve charge transport. Detaching the side chains in situ, 438 without compromising microstructural order, would increase backbone densification and performance. 439 Although promising in principle, most methods to remove the chains do so at the expense of order. 440 thereby detracting from transport properties. Molecular order has proved to be key in optimising 441 charge transport, so finding ways to further reduce disorder in conjugated systems, or otherwise 442 designing materials with a higher tolerance towards rotational fluctuations, will be essential to 443 improve charge transport. To date, the introduction of labile side chains has proven challenging as it is 444 difficult to predict the solid state packing of molecules and the different vibrational modes associated with a particular unit cell. With improvements in computational power, we have access to material 445 446 property predictions that are more sophisticated and accurate, such that they can provide important 447 insights into material packing motifs and phonon coupling modes. Thus, not only can we often 448 calculate the many phonon coupling modes in a conjugated system, but, importantly, we can predict 449 and identify the modes most detrimental to charge transport.

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451 Besides the transport of electronic charge through a solid, other phenomena such as mixed conduction — electronic and ionic charge transport — are also attracting increasing attention due to their potential applications in biological interfacing.^{64,65} In this context, an organic electrochemical 452 453 454 transistor (OECT), a three-terminal device that can be gated through an aqueous electrolyte, is emerging as a powerful tool for bioelectronic applications. In an OECT, the active layer exhibits both 455 456 electronic and ionic mobility throughout the bulk. Development of n- and p-type semiconducting 457 polymers for OECTs therefore necessitates new design rules for tuning the frontier orbitals. For stable 458 operation in aqueous environments, as a first prerequisite, the HOMO of p-type materials must be 459 electrochemically accessible — at a potential lower than that at which H_2O oxidation would take place (1.23 V versus the normal hydrogen electrode). High-performance mixed conductors have much 460 461 shallower HOMO levels, with E_{HOMO} between -4.4 and -4.6 eV, depending on the measurement technique.^{66,67} HOMO levels in this energy range can be obtained with glycolated polythiophenes 462 463 similar to poly(3-alkoxythiophene) (FIG. 3), in which the O atoms mesomerically donate electron 464 density to the polymer backbone while the polar nature of the oligoether side chain facilitates ion transport. The development of n-type semiconductors is essential to sense biologically-relevant 465 metabolites and cations, such as Na⁺, K⁺ and Ca²⁺. To be operationally stable in H₂O, the main 466 challenge centres around stabilizing the radical anion forms of the semiconductor towards H₂O and/or 467 O_2 .⁶⁸ This stability would dictate materials to have $E_{LUMO} < -4.0 \text{ eV}$.^{69,70} At present, the performance 468 of electron-transporting OECT semiconductors lags substantially behind their hole-transporting 469 470 counterparts. This lag has been tentatively attributed to coulombic charge-pinning from counterions, 471 charge-trapping from H₂O, and other phenomena. Clearly, new molecular designs for electron 472 transport in aqueous environments are required to overcome these limitations.

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474 To develop organic semiconductors for photovoltaic applications, focus should not be on optimising 475 the electronic and solid-state properties of a single material, but rather on understanding how to 476 deliberately control the morphology of an active layer. This might entail, for example, incorporating 477 multiple materials that are chosen to set up an energy cascade with large CT state energies. While the 478 frontier orbital energy levels and the isolated molecular packing of both donor and acceptor can in 479 general be controlled, there is presently a lack in understanding how functionalization of an organic 480 molecule will affect its solid morphology on microscopic and macroscopic length scales. Using less-481 diffusive NFAs does help the morphological stability of a BHJ blend but it would be highly 482 advantageous if the tertiary structure could be controlled to a greater extent, for instance by choice of 483 heteroatoms, functional groups and side chains. Ideally, such approaches should also provide a means 484 to 1) generate much thicker photoactive layers without unwanted vertical phase separation and 485 excessive charge recombination and 2) scale up the cell's active area more effortlessly to generate 486 large devices for beneficial practical implications. Over much shorter length scales, being able to 487 control the donor: acceptor interfaces in the blend, for instance through molecular shape and dipole 488 moments, would allow for greater understanding and control of the energy-transfer and charge-489 transfer processes. Another important aspect that requires further attention is the role of the CT state, 490 how the CT state can be manipulated through chemical design and how this can be used to suppress 491 recombination processes. Recent work indicates that electrostatic potential mapping, for instance, 492 could be a useful and rapid tool to help understand how molecular structure and intermolecular interactions influence the charge separation processes.⁷¹ The recent reports describing $\mathbf{Y6}$, a curved 493

494 NFA structure markedly different from the previous best NFA performers in terms of molecular 495 design, have to a large extent taken the OPV community by surprise. This promising example shows 496 that there is still ample room to improve device performance, and also highlights the lack of unified 497 molecular design criteria. Detailed structure-property relationships of NFAs and the main reasons for 498 their excellent performance continue to be explored. Factors such as their off-axis dipoles, high 499 electron mobilities, facile energy transfer processes and potential for good Förster energy overlap with 500 donors could play important roles. As the OPV research community now embarks on in-depth 501 fundamental studies of devices based on Y6 and its analogues, further pieces of this puzzle will 502 emerge. This insight will push the device performance closer towards the 20% efficiency mark and 503 hopefully add to the understanding of molecular and frontier energy level design criteria.

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505 The commercialization of OLED technologies has already been a monumental success. However, we 506 lack a detailed understanding of the exact photophysical processes at play during charge 507 recombination and emission. Moreover, we require a clear relationship between chemical structure 508 and photophysical properties to rationally design new materials and realize progress. It is necessary to 509 further understand the origin of the stability/instability of excited states, in particular in the presence 510 of charges. Identifying degradation pathways may allow us to come up with chemical modifications 511 enhance the stability of emitters. Despite this, present generations of OLED materials are operating 512 close to their theoretical maxima and for a step-change in performance, a new generation of materials must be developed. Some encouraging signs of emerging 4th generation materials that warrant 513 exploration are emerging. For example, there have been recent reports of extremely efficient OLED devices based on radical fluorophores.^{72,73} These compounds, which feature the well-known 514 515 516 luminescent tris(2,4,6-trichlorophenyl)methyl (TTM) radical motif, emit from a doublet excited state 517 such that recombination is independent of the excited state spin. However, thus far these materials 518 have only exhibited electroluminescence in the red/near-infrared and it remains to be seen whether it 519 is possible to tune them to cover the entire visible spectrum. Another interesting new approach 520 involves the use of host materials that can undergo singlet fission, which, in principle, could allow for 521 IQEs of 200%.⁷⁴ Yet, such a device fashioned using the emitter $[Er^{III}(8-hydroxyquinolinato)_3]$ as the 522 guest in a rubrene singlet fission host gave a very low EQE, likely due to the low PLQY of the Er(III) 523 complex. Thus, in order for this strategy to succeed it will be necessary to not only develop wide 524 band-gap singlet fission hosts but also highly emissive near-infrared emitters capable of harvesting 525 triplet excitons. There have been several recent reports of OLEDs that exploit triplet fusion, whereby two triplets annihilate and produce an emissive singlet.⁷⁵⁻⁷⁷ Although this limits IQE to a maximum of 526 50% (if only triplets are injected), it could allow for low driving voltages and may offer blue emitters 527 528 with greater photostability than present compounds.

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530 There is a need to improve the chemistry used to synthesize organic semiconductors. The presence of 531 (often hard to detect) residual impurities can result in batch-to-batch variations or unintentional 532 doping. The availability and compatibility of chemical building blocks dictates the choice of reactions 533 used in synthetic routes. For example, polymerizations often rely on Pd-catalysed cross-couplings, 534 such as the Yamamoto, Suzuki-Miyaura, and Stille reactions. Although these coupling are extremely 535 efficient, their low atom economy and requirement (in the case of the present polyaromatic substrates) 536 for chlorinated solvents does not comply with sustainability requirements. Further, these reactions are 537 not particularly suitable for large-scale production. C-H activation and condensation chemistry circumvent some of these problems by shortening the synthetic pathway and making extensive functionalization of monomers obsolete.⁷⁸ The narrow scope and restrictions on what building blocks 538 539 are accessible leave ample room for improvement. Developing new chemical polymerisation 540 541 protocols that allow for control over molecular weight and polydispersity whilst reducing chemical 542 defects (that might occur on, for example, homocoupling or partial oxidation) will be an integral to 543 advance the quality of synthesised materials.

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741	perform	nance of organic semiconductors. Nat. Rev. Chem. 4, xxxxx (2020).	
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744	Many p	present and emerging electronic devices make use of organic semiconductors in view of their	
745	readily tuneable atomic and electronic structures. This Review describes the importance of analytical		
746	and computational tools in studying the molecules as well as their hierarchical self-assemblies, in		
747	which t	he motion of charges and excited states govern device properties.	
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749	Subject	terms	
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- 753

754 Captions

755 Fig. 1 | Manipulating frontier orbital distributions and energies. A series of conjugated aryl 756 molecules differing in aromatic units and substituent functionality is shown to exhibit contrasting 757 distributions and energies of their highest occupied molecular orbital (HOMO) and lowest unoccupied 758 molecular orbital (LUMO). Ground state geometries and HOMO wavefunction distributions were 759 obtained using density functional theory with the B3LYP method and def2-SVP basis set, using 760 Grimme's D3 dispersion correction and the BJ damping function. Time-dependent density functional 761 theory, along with the ground state coordinates, was used at the same level of theory to calculate the 762 LUMO wavefunction distributions.

763

Fig. 2 | Schematic illustrations and chemical structures of conjugated thiophene-derived polymers. a | The 3D packing arrangement of pBTTT enables electron transport across and between its crystalline domains⁷. b | In contrast, **IDT-BT** exists as disordered chains, through which electrons can move⁹. The chains intermittently contact another chain or region, to/from which the electrons can move. The arrows illustrate a possible optimal pathway for electron transport. R represents alkyl side chains.

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Fig. 3 | Species that may find applications in organic field effect transistors. a | Chemical structures of poly(3-alkoxy)thiophene, diketopyrrolopyrrole and isoindigo, with attractive planarizing interactions highlighted in green and orange. b | Chemical structures of high-performance molecular polyaromatic semiconductors **TIPS-pentacene**, **TES-ADT** and **C**₈-**BTBT**. R depicts alkyl side groups.

776

Fig. 4 | Donor:acceptor bulk heterojunctions and some typical semiconducting components. a |
Energy diagrams depicting the donor-acceptor electronic band alignment and photocurrent generation
through a channel-I or II mechanism. b | Archetypical electron donors, which evolved from the early
poly(3-hexylthiophene) P3HT to the more elaborate structures on the right. c | Archetypical electron
acceptors. R describes solubilising side groups, such as linear and branched alkyl chains.

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Fig. 5 | The evolution of molecular organic light emitters. 1st generation emitters rely on
fluorescence between singlet states, with subsequent developments leading to the development of 2nd
generation emitters, in which intersystem crossing (ISC) from singlet to triplet states is followed by
phosphorescence. Examples of the most recent paradigm, the 3rd generation emitters, exhibit
thermally-activated delayed fluorescence, in which ISC is followed by reverse intersystem crossing
(RISC).

790 BOX 1 | Energy levels in an isolated organic molecule and a molecular crystal or polymer.

Isolated organic semiconductor moieties have discrete HOMO and LUMO energy levels, which are broadened into electronic bands — the valence and conduction band, respectively — when the moieties aggregate, either in terms of individual molecules in a solid or moieties connected as part of a polymer. The optical band gap E_g is the difference in energy between the highest energy of the valence band and the lowest energy of the conduction band. The IP is the energy required to remove one electron from the top of the valence band, whereas the EA is the energy released by adding one electron from the vacuum level to the bottom of the conduction band.

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